

MOS FIELD EFFECT TRANSISTOR

μ PA2744UT1A

SWITCHING

N-CHANNEL POWER MOSFET

DESCRIPTION

The μ PA2744UT1A is N-channel MOS Field Effect Transistor designed for DC/DC converter applications.

FEATURES

- Low on-state resistance
- $R_{DS(on)1} = 2.0 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = 10 \text{ V}$, $I_D = 65 \text{ A}$)
- $R_{DS(on)2} = 2.9 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = 4.5 \text{ V}$, $I_D = 33 \text{ A}$)
- Low Q_G
- Thin type surface mount package with heat spreader (8-pin HVSON)
- RoHS Compliant
- Halogen Free

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, All terminals are connected.)

Drain to Source Voltage ($V_{GS} = 0 \text{ V}$)	V_{DSS}	30	V
Gate to Source Voltage ($V_{DS} = 0 \text{ V}$)	V_{GSS}	± 20	V
Drain Current (DC) ($T_C = 25^\circ\text{C}$)	$I_{D(DC)}$	± 65	A
Drain Current (pulse) ^{Note1}	$I_{D(pulse)}$	± 260	A
Total Power Dissipation ^{Note2}	P_{T1}	1.5	W
Total Power Dissipation ($PW = 10 \text{ sec}$) ^{Note2}	P_{T2}	4.6	W
Total Power Dissipation ($T_C = 25^\circ\text{C}$)	P_{T3}	83	W
Channel Temperature	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	$-55 \text{ to } +150$	$^\circ\text{C}$
Single Avalanche Current ^{Note3}	I_{AS}	40	A
Single Avalanche Energy ^{Note3}	E_{AS}	160	mJ

THERMAL RESISTANCE

Channel to Ambient Thermal Resistance ^{Note2}	$R_{th(ch-A)}$	83.3	$^\circ\text{C/W}$
Channel to Case (Drain) Thermal Resistance	$R_{th(ch-C)}$	1.5	$^\circ\text{C/W}$

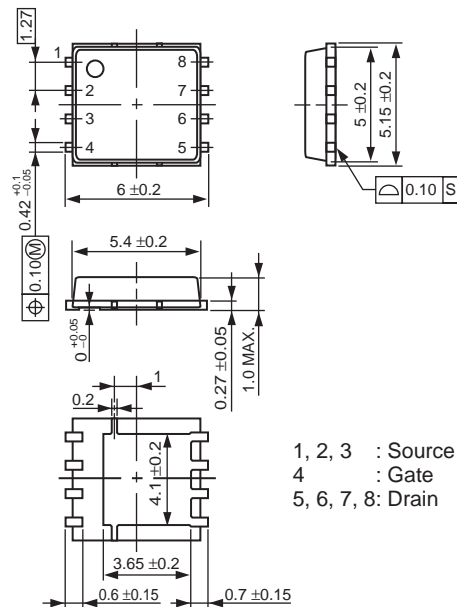
- Notes**
1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$
 2. Mounted on a glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mm
 3. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = 15 \text{ V}$, $R_G = 25 \Omega$, $V_{GS} = 20 \rightarrow 0 \text{ V}$, $L = 100 \mu\text{H}$

Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

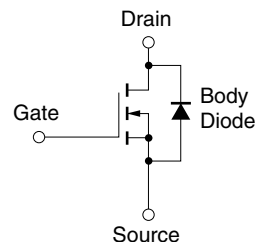
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PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT

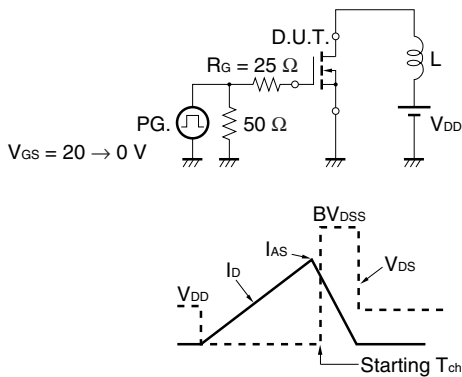


ELECTRICAL CHARACTERISTICS (T_A = 25°C, All terminals are connected.)

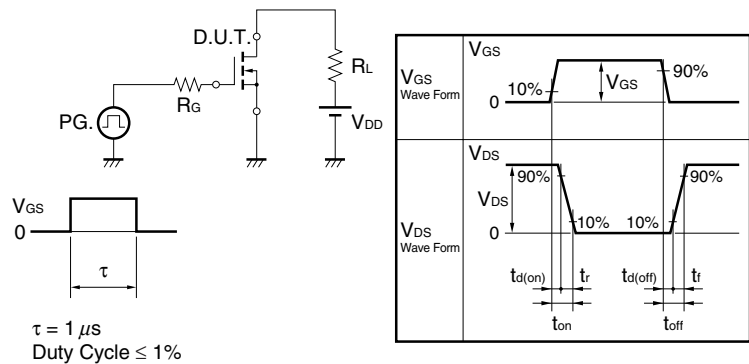
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V			±100	nA
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5		2.5	V
Forward Transfer Admittance ^{Note}	y _{fs}	V _{DS} = 10 V, I _D = 33 A	30			S
Drain to Source On-state Resistance ^{Note}	R _{DSON1}	V _{GS} = 10 V, I _D = 65 A		1.6	2.0	mΩ
	R _{DSON2}	V _{GS} = 4.5 V, I _D = 33 A		2.3	2.9	mΩ
Input Capacitance	C _{iss}	V _{DS} = 15 V, V _{GS} = 0 V,		5370	6980	pF
Output Capacitance	C _{oss}	f = 1 MHz		910	1180	pF
Reverse Transfer Capacitance	C _{rss}			410	620	pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 15 V, I _D = 33 A,		33		ns
Rise Time	t _r	V _{GS} = 10 V,		18		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		115		ns
Fall Time	t _f			25		ns
Total Gate Charge	Q _G	V _{GS} = 10 V		84	128	nC
		V _{GS} = 5 V		43	66	nC
Gate to Source Charge	Q _{GS}	V _{DD} = 15 V		19		nC
Gate to Drain Charge	Q _{GD}	I _D = 65 A		13		nC
Body Diode Forward Voltage ^{Note}	V _{F(S-D)}	I _F = 65 A, V _{GS} = 0 V		0.83		V
Reverse Recovery Time	t _{rr}	I _F = 65 A, V _{GS} = 0 V,		45		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 100 A/μs		46		nC
Gate Resistance	R _G	f = 1 MHz		1.3	2.1	Ω

Note Pulsed

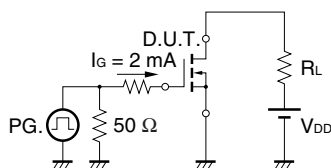
TEST CIRCUIT 1 AVALANCHE CAPABILITY



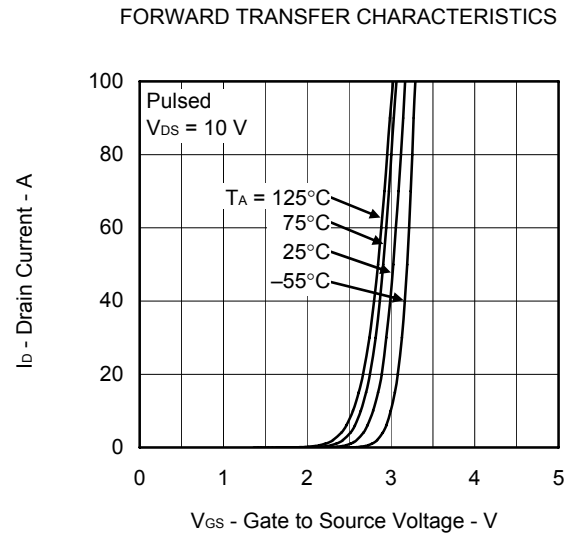
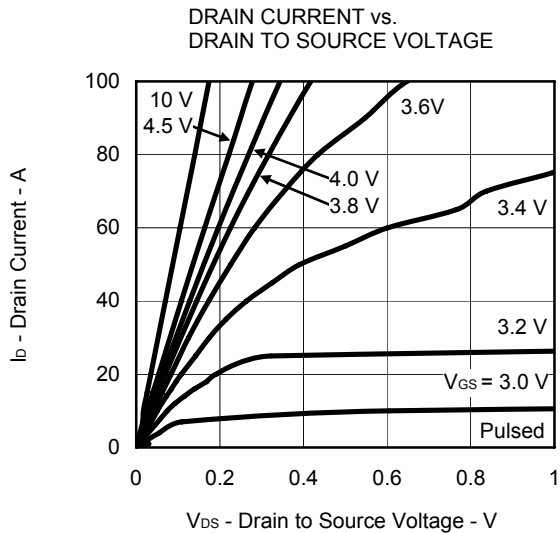
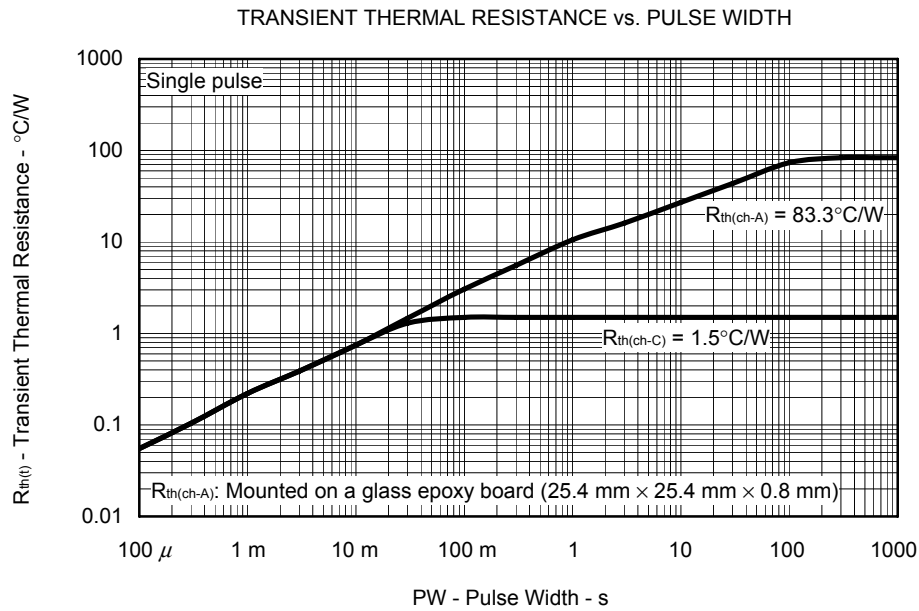
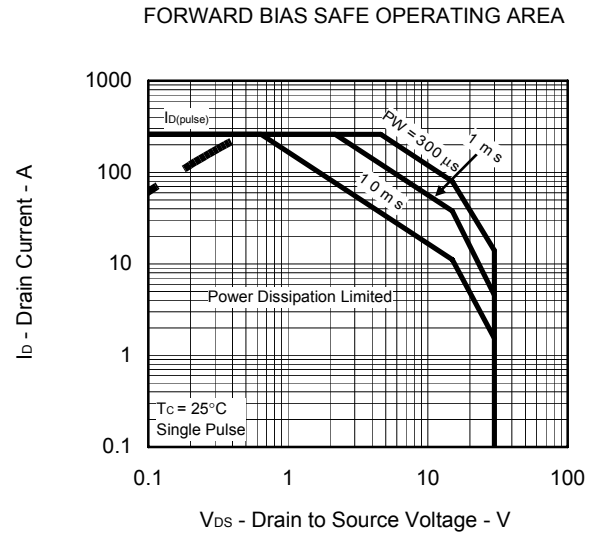
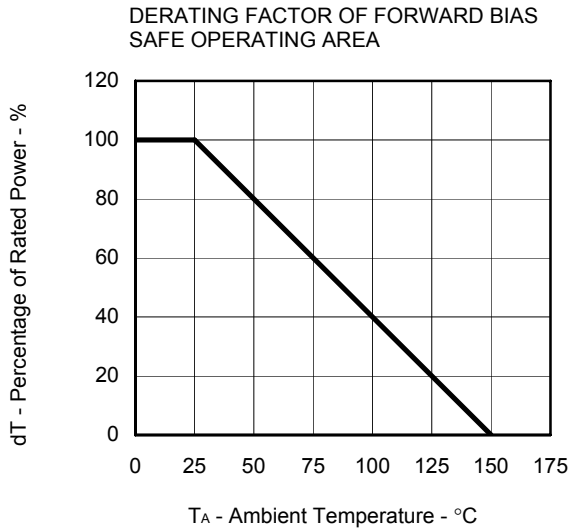
TEST CIRCUIT 2 SWITCHING TIME



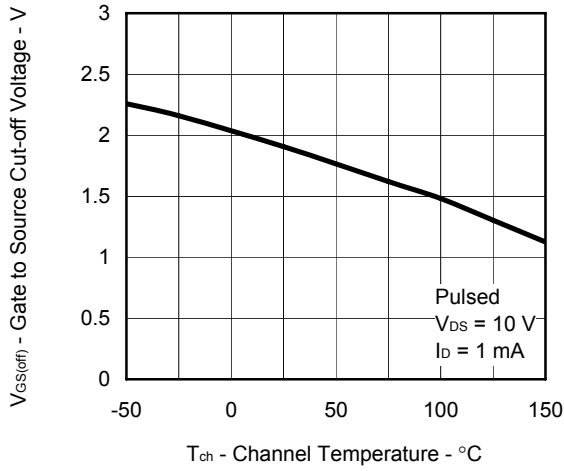
TEST CIRCUIT 3 GATE CHARGE



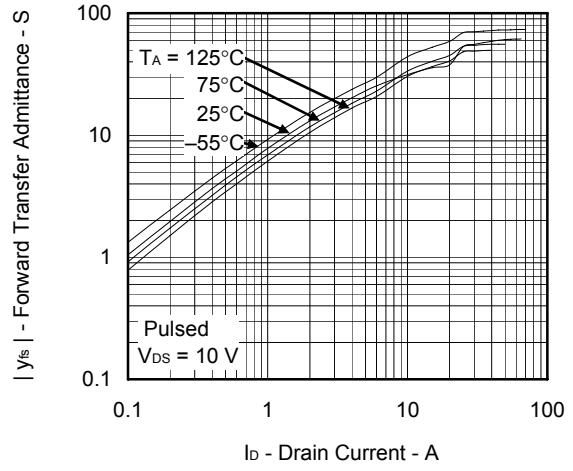
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



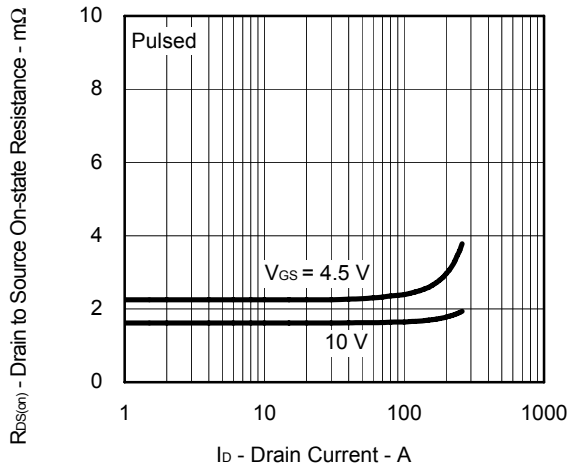
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



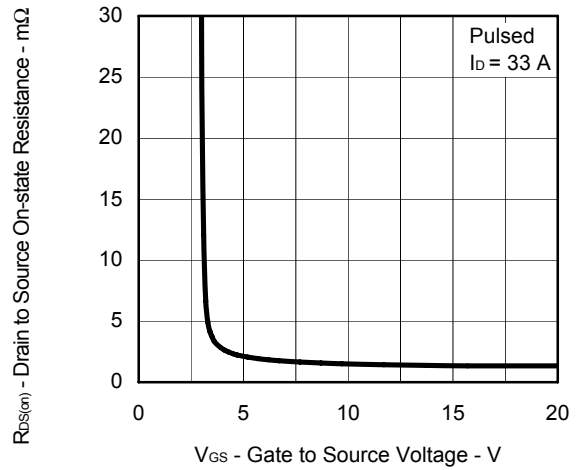
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



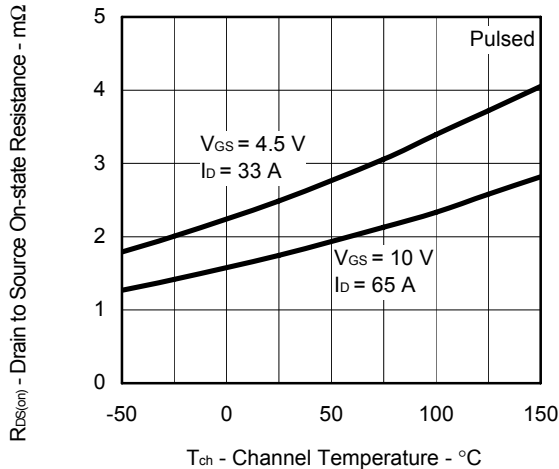
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



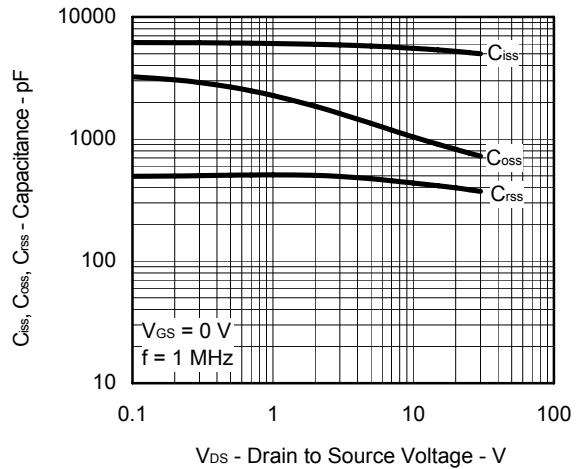
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



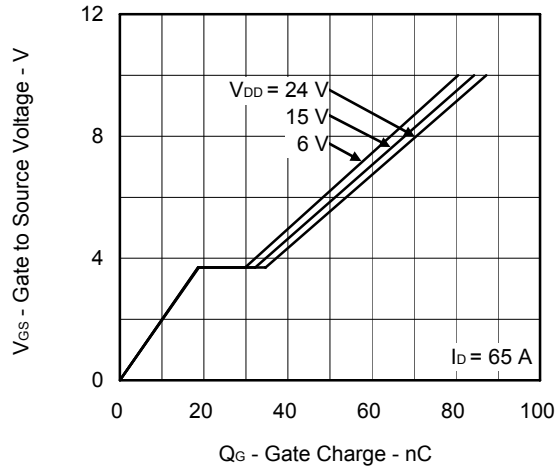
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



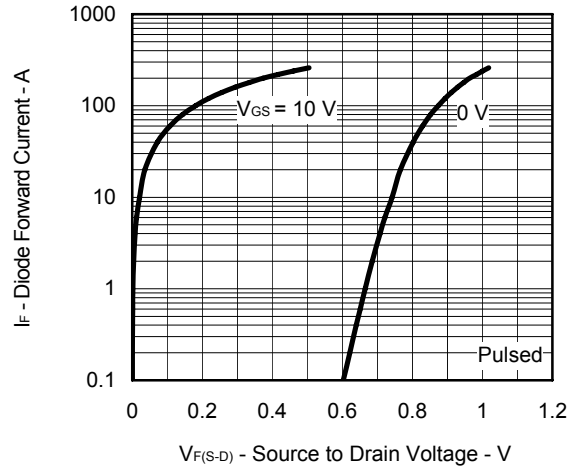
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



DYNAMIC INPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
μPA2744UT1A-E1-AY ^{Note}	Pure Sn	Tape 3000 p/reel	8-pin HVSON (6051) 0.10 g TYP.
μPA2744UT1A-E2-AY ^{Note}			

Note Pb-free (This product does not contain Pb in the external electrode.)

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